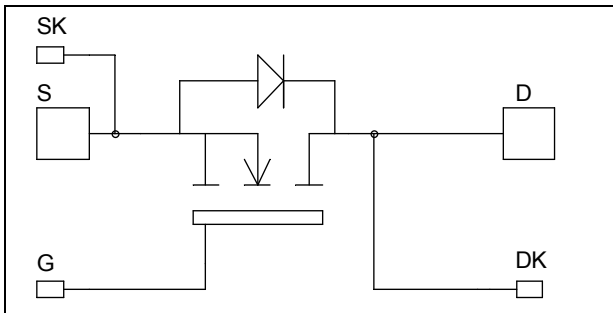


## Single Switch MOSFET Power Module

$V_{DSS} = 1000V$   
 $R_{DSon} = 60m\Omega \text{ typ @ } T_j = 25^\circ C$   
 $I_D = 129A \text{ @ } T_c = 25^\circ C$

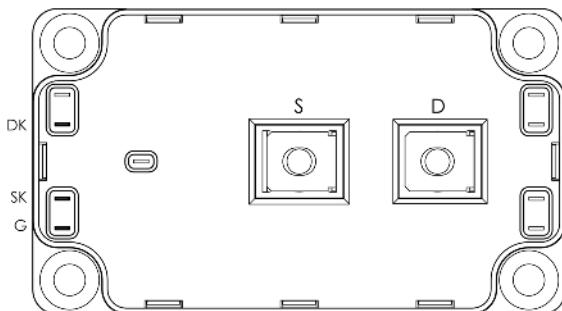


### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance




### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	1000	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	129
		$T_c = 80^\circ C$	97
$I_{DM}$	Pulsed Drain current	516	A
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	70	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	2272
$I_{AR}$	Avalanche current (repetitive and non repetitive)	25	A
$E_{AR}$	Repetitive Avalanche Energy	50	mJ
$E_{AS}$	Single Pulse Avalanche Energy	3000	


**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$			600	$\mu\text{A}$
		$V_{GS} = 0V, V_{DS} = 800V$			3	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 64.5A$		60	70	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 15\text{mA}$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 500$	$\text{nA}$

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1\text{MHz}$		31.1		$\text{nF}$
$C_{oss}$	Output Capacitance			5.28		
$C_{rss}$	Reverse Transfer Capacitance			0.96		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 500V$ $I_D = 129A$		1116		$\text{nC}$
$Q_{gs}$	Gate – Source Charge			144		
$Q_{gd}$	Gate – Drain Charge			732		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 129A$ $R_G = 0.8\Omega$		18		$\text{ns}$
$T_r$	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			155		
$T_f$	Fall Time			40		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>25^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 129A, R_G = 0.8\Omega$		5.4		$\text{mJ}$
$E_{off}$	Turn-off Switching Energy			3.7		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 129A, R_G = 0.8\Omega$		8.5		$\text{mJ}$
$E_{off}$	Turn-off Switching Energy			4.7		

**Source - Drain diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
$I_S$	Continuous Source current (Body diode)	$T_c = 25^\circ\text{C}$			129	A	
		$T_c = 80^\circ\text{C}$			97		
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -129A$			1.3	V	
$dv/dt$	Peak Diode Recovery <sup>①</sup>				18	V/ns	
$t_{rr}$	Reverse Recovery Time	$I_S = -129A$ $V_R = 670V$ $di_S/dt = 600A/\mu\text{s}$	$T_j = 25^\circ\text{C}$			320	$\text{ns}$
			$T_j = 125^\circ\text{C}$			650	
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$			21.6	$\mu\text{C}$
			$T_j = 125^\circ\text{C}$			58.3	

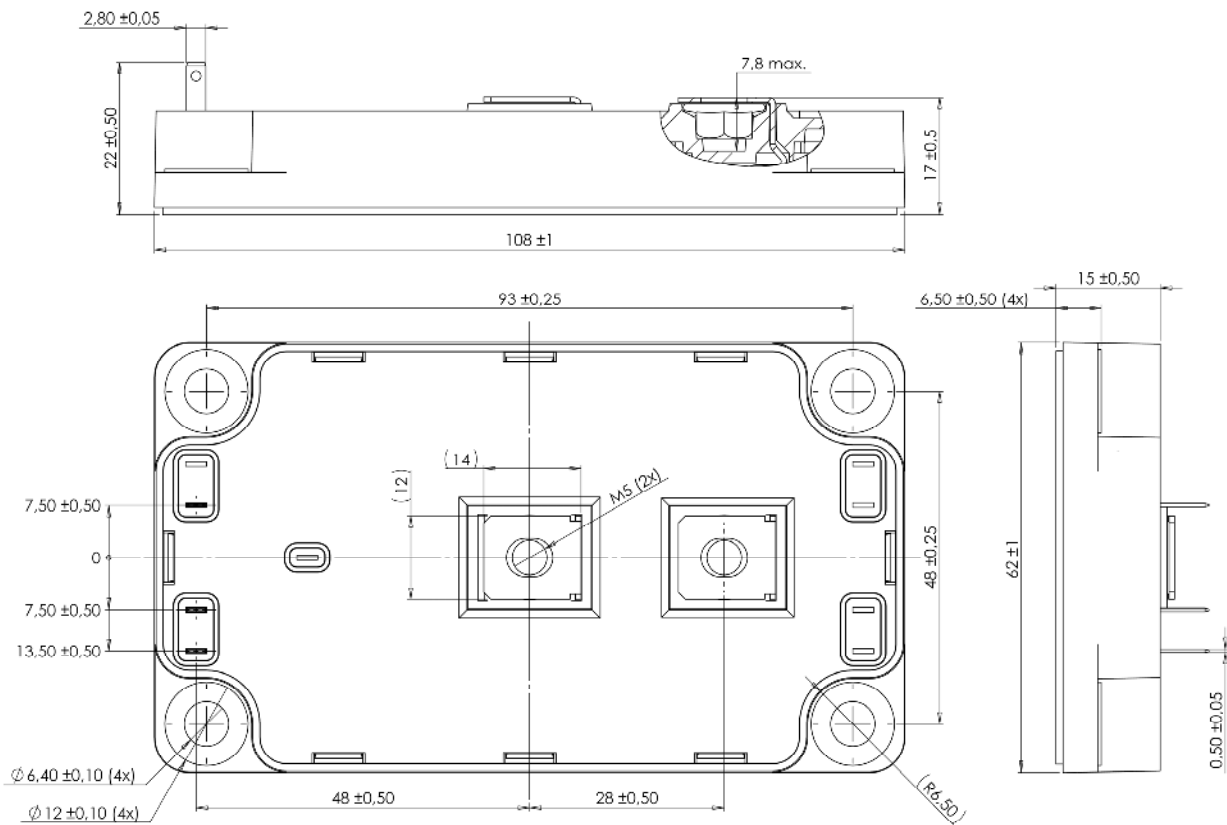
<sup>①</sup>  $dv/dt$  numbers reflect the limitations of the circuit rather than the device itself.

$$I_S \leq -129A \quad di/dt \leq 700A/\mu\text{s} \quad V_R \leq V_{DSS} \quad T_j \leq 150^\circ\text{C}$$

## Thermal and package characteristics

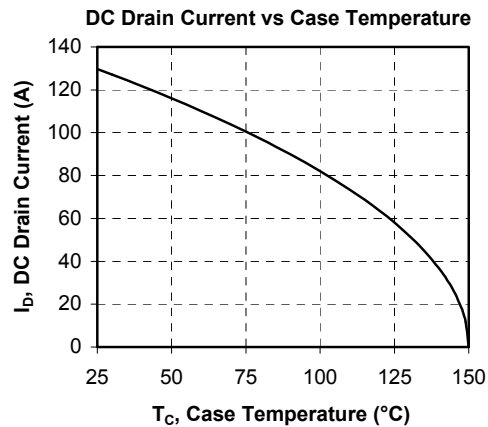
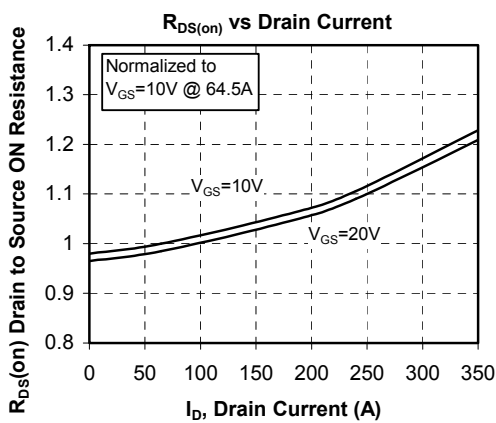
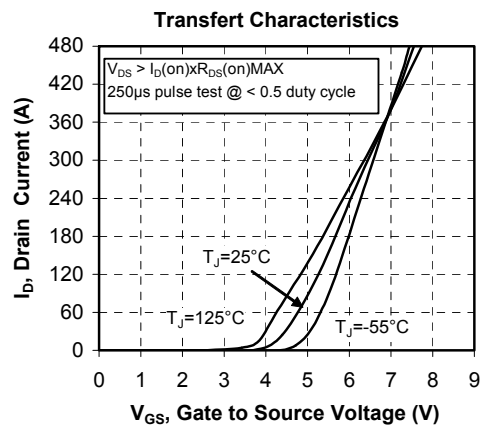
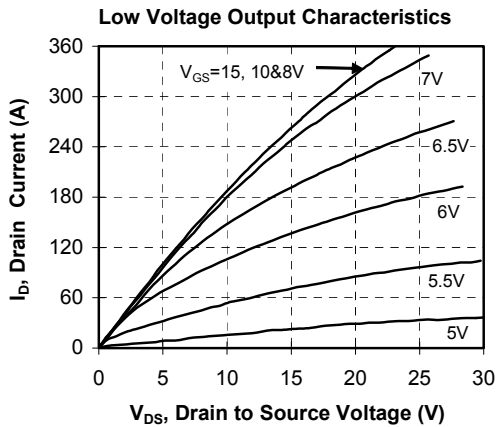
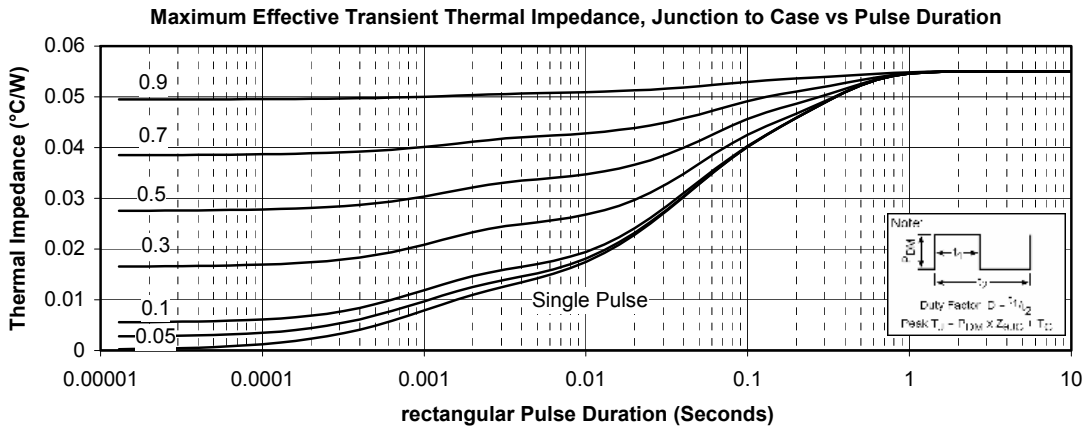
Symbol	Characteristic	Min	Typ	Max	Unit	
$R_{thJC}$	Junction to Case Thermal Resistance			0.055	°C/W	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000			V	
$T_J$	Operating junction temperature range	-40		150	°C	
$T_{STG}$	Storage Temperature Range	-40		125		
$T_C$	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight			300	g	

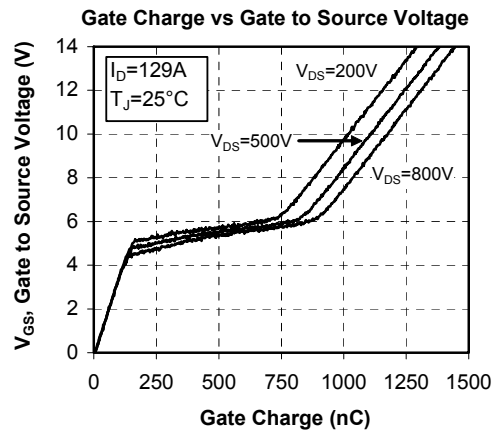
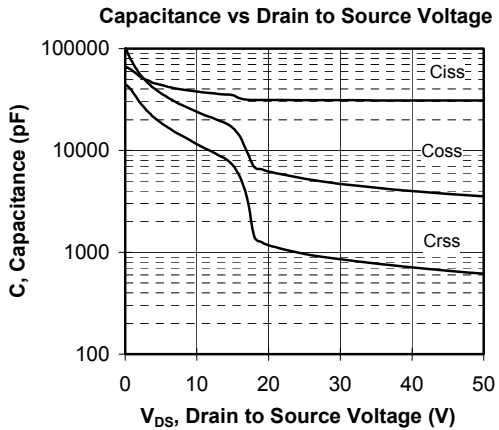
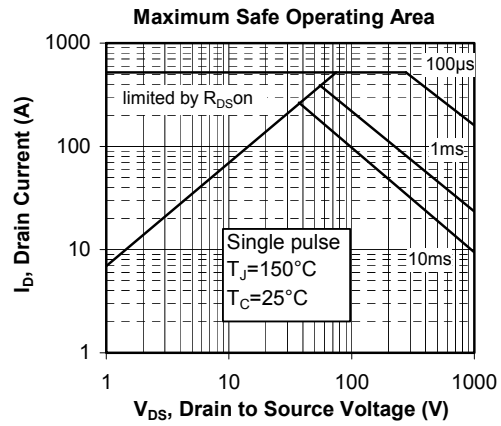
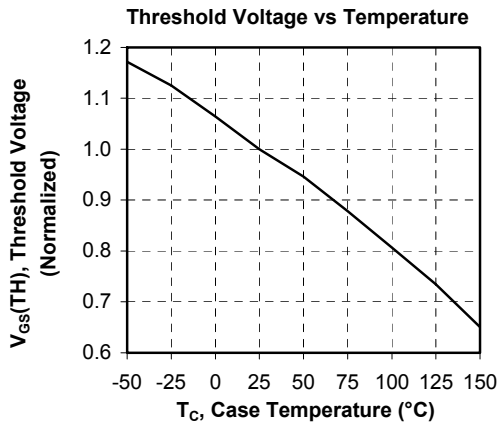
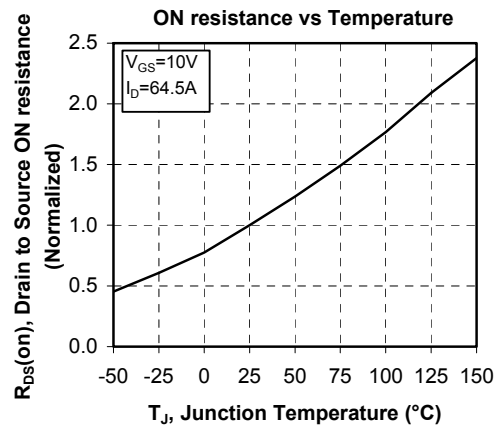
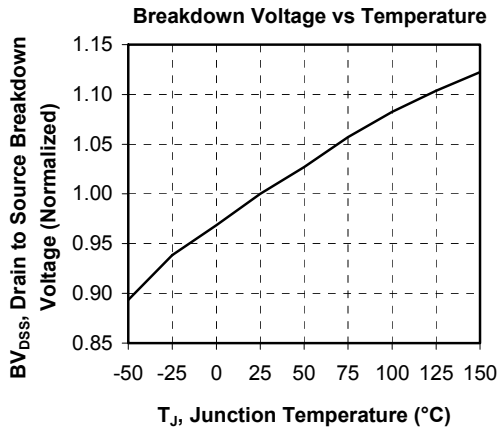
## SP6 Package outline (dimensions in mm)

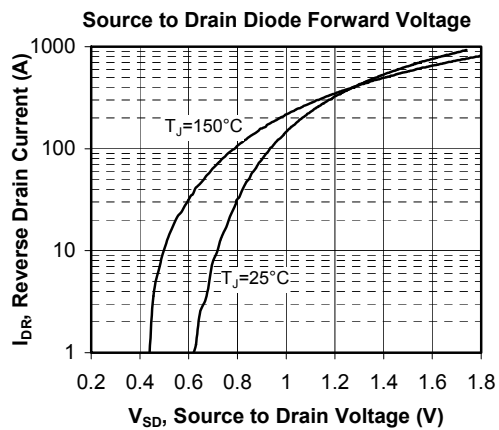
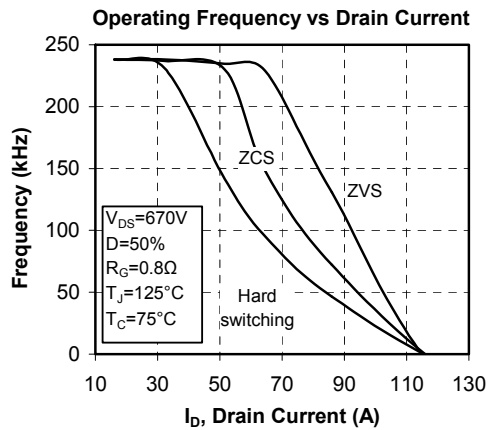
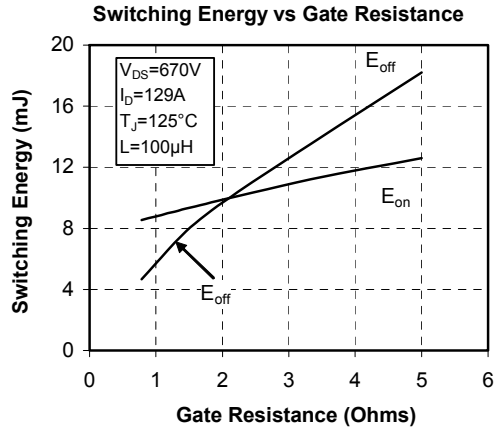
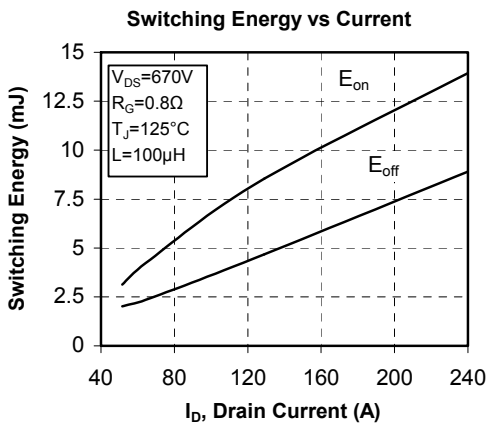
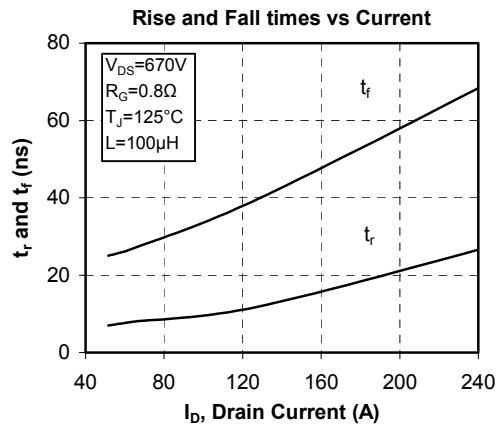
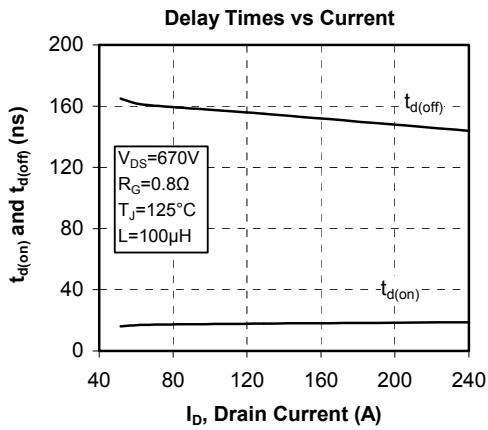


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve







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